250 V, 40 A SWITCHMODE™ **Schottky Power Rectifier**

Features

- 250 V Blocking Voltage
- Low Forward Voltage Drop, V_F = 0.86 V
- Soft Recovery Characteristic, T_{RR} < 35 ns
- Stable Switching Performance Over Temperature
- These are Pb-Free Devices*

Benefits

- Reduces or Eliminates Reverse Recovery Oscillations
- Minimizes Need for EMI Filtering
- Reduces Switching Losses
- Improved Efficiency

Applications

- Power Supply
- Power Management
- Automotive
- Instrumentation

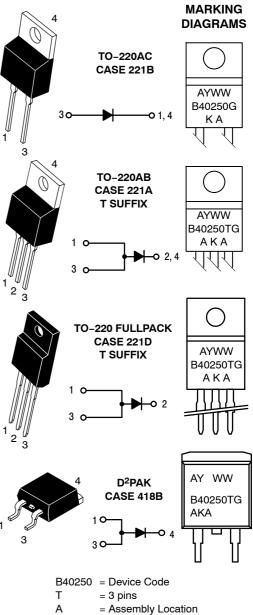
Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Epoxy Meets UL 94 V-0 at 0.125 in



ON Semiconductor®

http://onsemi.com



= Year

WW = Work Week

= Pb-Free Package KA, AKA = Polarity Designator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	250	V
Average Rectified Forward Current (Rated V_R) T_C = 82°C MBR40250, MBR40250T, MBRB40250T (Rated V_R) T_C = 46°C MBRF40250T	I _{F(AV)}	40	А
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz) T_C = 82°C MBR40250, MBR40250T, MBRB40250T (Rated V_R , Square Wave, 20 kHz) T_C = 46°C MBRF40250T	I _{FRM}	80	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	150	Α
Storage Temperature	T _{stg}	-65 to +175	°C
Operating Junction Temperature	T_J	- 65 to +150	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Ratin	Symbol	Value	Unit	
Maximum Thermal Resistance	Junction-to-Case MBR40250(T) and MBRB40250T MBRF40250 Junction-to-Ambient MBR40250(T) MBRF40250 MBRB40250T	R _{θJA}	2.0 3.0 60 50 50	°C/W

ELECTRICAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 1) $I_F=20~A,~T_C\\I_F=20~A,~T_C\\I_F=40~A,~T_C\\I_F=40~A,~T_C=1$	= 125°C = 25°C	0.86 0.71 0.97 0.86	V
Maximum Instantaneous Reverse Current (Note 1) $ \begin{array}{c} \text{Rated DC Voltage, T}_C \\ \text{Rated DC Voltage, T}_C \end{array} $	= 25°C = 125°C	0.25 30	mA
Maximum Reverse Recovery Time $I_F = 1.0 \ A, \ di/dt = 50 \ A/\mu s, \ T_C$	= 25°C	35	ns

DYNAMIC CHARACTERISTICS

Capacitance	$V_R = -5.0 \text{ V}, T_C = 25^{\circ}\text{C}, \text{ Frequency} = 1.0 \text{ MHz}$	C _T	500	pF

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

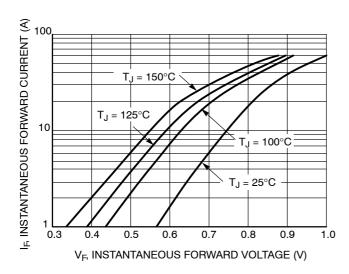
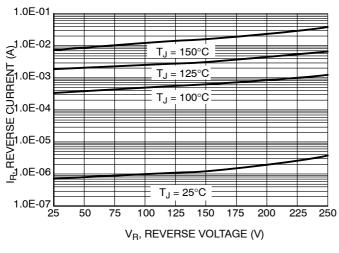


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage



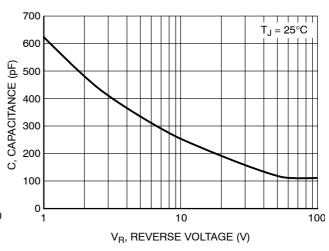
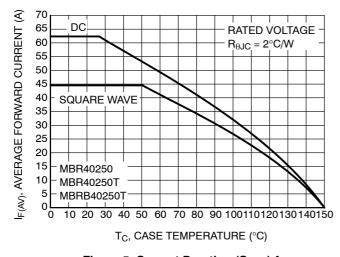


Figure 3. Typical Reverse Current

Figure 4. Typical Capacitance



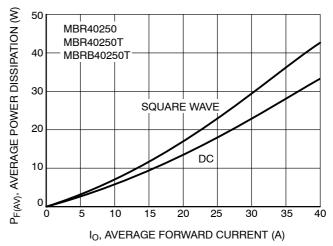
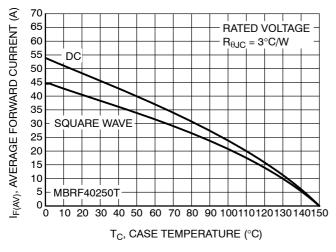


Figure 5. Current Derating (Case) for MBR40250, MBR40250T and MBRB40250T

Figure 6. Forward Power Dissipation for MBR40250, MBR40250T and MBRB40250T

TYPICAL CHARACTERISTICS



SQUARE WAVE

SQUARE WAVE

10

SQUARE WAVE

10, AVERAGE FORWARD CURRENT (A)

Figure 7. Current Derating (Case) for MBRF40250T

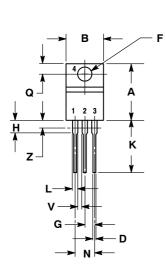
Figure 8. Forward Power Dissipation for MBRF40250T

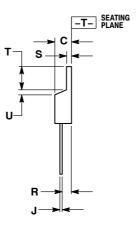
ORDERING INFORMATION

Device	Package	Shipping [†]
MBR40250G	TO-220AC (Pb-Free)	50 Units / Rail
MBR40250TG	TO-220AB (Pb-Free)	50 Units / Rail
MBRF40250TG	TO-220 FULLPACK (Pb-Free)	50 Units / Rail
MBRB40250TG	D ² PAK (Pb-Free)	50 Units / Rail
MBRB40250TT4G	D ² PAK (Pb-Free)	800 Units / Tape & Reel

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**





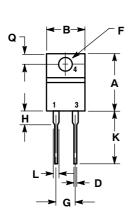
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

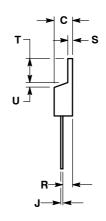
	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 6: PIN 1. ANODE 2. CATHODE

 - 3. ANODE 4. CATHODE

TO-220AC CASE 221B-04 ISSUE E



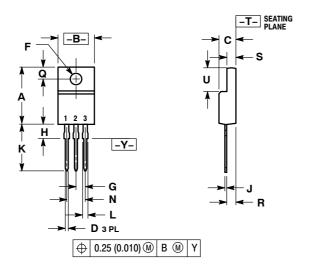


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

PACKAGE DIMENSIONS

TO-220 FULLPAK CASE 221D-03 **ISSUE J**

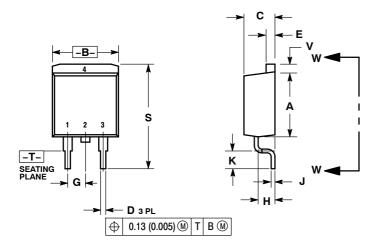


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH
 3. 221D-01 THRU 221D-02 OBSOLETE, NEW STANDARD 221D-03.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.617	0.635	15.67	16.12
В	0.392	0.419	9.96	10.63
C	0.177	0.193	4.50	4.90
D	0.024	0.039	0.60	1.00
F	0.116	0.129	2.95	3.28
G	0.100 BSC		2.54	BSC
H	0.118	0.135	3.00	3.43
7	0.018	0.025	0.45	0.63
K	0.503	0.541	12.78	13.73
L	0.048	0.058	1.23	1.47
N	0.200	0.200 BSC		BSC
œ	0.122	0.138	3.10	3.50
R	0.099	0.117	2.51	2.96
S	0.092	0.113	2.34	2.87
J	0.239	0.271	6.06	6.88

PACKAGE DIMENSIONS

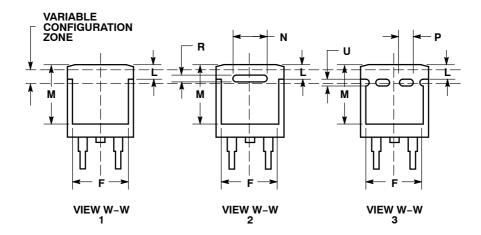
D²PAK 3 CASE 418B-04 ISSUE K



NOTES:

- 1. DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES MILLIMETE		IETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
В	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
Е	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54	BSC
Н	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
M	0.280	0.320	7.11	8.13
N	0.197 REF		5.00 REF	
Р	0.079 REF		2.00 REF	
R	0.039	REF	0.99	REF
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40



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